

# BIPOLAR ANALOG INTEGRATED CIRCUIT $\mu PC8112TB$

# SILICON MMIC 1st FREQUENCY DOWN-CONVERTER FOR CELLULAR/CORDLESS TELEPHONE

#### DESCRIPTION

The  $\mu$ PC8112TB is a silicon monolithic integrated circuit designed as 1st frequency down-converter for cellular/cordless telephone receiver stage. This IC consists of mixer and local amplifier. The  $\mu$ PC8112TB features high impedance output of open collector. Similar ICs of the  $\mu$ PC2757TB and  $\mu$ PC2758TB feature low impedance output of emitter follower. These TB suffix ICs which are smaller package than conventional T suffix ICs contribute to reduce your system size.

The  $\mu$ PC8112TB is manufactured using the 20 GHz fr NESAT<sup>M</sup>III silicon bipolar process. This process uses silicon nitride passivation film and gold electrodes. These materials can protect chip surface from external pollution and prevent corrosion/migration. Thus, this IC has excellent performance, uniformity and reliability.

#### **FEATURES**

• Excellent RF performance :	IIP <sub>3</sub> = $-7 \text{ dBm}@f_{RFin} = 1.9 \text{ GHz}$ (reference)
	$IM_3 = -88 \text{ dBm} @ P_{RFin} = -38 \text{ dBm}, 1.9 \text{ GHz}$ (reference)
• Similar conversion gain to $\mu$ PC	2757 and lower noise figure than $\mu$ PC2758
Minimized carrier leakage	RFLO = -80 dB@fRFin = 900 MHz (reference)
	RFLO = -55 dB@fRFin = 1.9 GHz (reference)
High linearity :	Po(sat) = -2.5 dBm TYP.@fRFin = 900 MHz
	$PO(sat) = -3 \text{ dBm TYP}.@f_{RFin} = 1.9 \text{ GHz}$
Low current consumption	Icc = 8.5  mA TYP.
Supply voltage :	Vcc = 2.7 to 3.3 V
High-density surface mounting:	6-pin super minimold package

#### **APPLICATIONS**

- 1.5 to 1.9 GHz cellular/cordless telephone (PHS, DECT, PDC1.5G and so on)
- 800 to 900 MHz cellular telephone (PDC800M and so on)

#### ORDER INFORMATION

Part Number	Package	Markings	Supplying Form
μPC8112TB-E3-A	6-pin super minimold	C2K	Embossed tape 8 mm wide. Pin 1, 2, 3 face the tape perforation side. Qty 3kpcs/reel.

**Remark** To order evaluation samples, please contact your local nearby sales office (Part number for sample order: μPC8112TB-A).

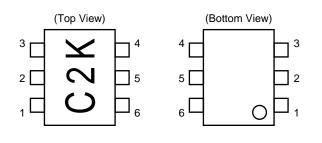
#### Caution Electro-static sensitive devices

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#### **1. PIN CONNECTIONS**



		-
n No.	Pin Name	
1	RFinput	
2	GND	
3	LOinput	
4	PS	
5	Vcc	
6	IFoutput	
		-

# 2. PRODUCT LINE-UP (TA = +25°C, Vcc = VPS = 3.0 V, ZS = ZL = 50 $\Omega$ )

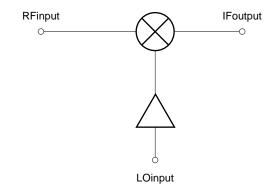
ltems Part Number	No RF Icc (mA)	900 MHz SSB · NF (dB)	1.5 GHz SSB · NF (dB)	1.9 GHz SSB · NF (dB)	900 MHz CG (dB)	1.5 GHz CG (dB)	1.9 GHz CG (dB)	900 MHz IIP3 (dBm)	1.5 GHz IIP₃ (dBm)	1.9 GHz IIP₃ (dBm)
μPC2757T	5.6	10	10	13	15	15	13	-14	-14	-12
μPC2757TB										
μPC2758T	11	9	10	13	19	18	17	-13	-12	-11
μPC2758TB										
μPC8112T	8.5	9	11	11	15	13	13	-10	-9	-7
μPC8112TB										

ltems Part Number	900 MHz P <sub>O(sat)</sub> (dBm)	1.5 GHz Po <sub>(sat)</sub> (dBm)	1.9 GHz Po <sub>(sat)</sub> (dBm)	900 MHz RFL0 (dB)	1.5 GHz RFLO (dB)	1.9 GHz RFLO (dB)	IF Output Configuration	Package
μPC2757T	-3	-	-8		-	-	Emitter follower	6-pin minimold
μPC2757TB								6-pin super minimold
μPC2758T	+1	-	-4	_	-	-		6-pin minimold
μPC2758TB								6-pin super minimold
μPC8112T	-2.5	-3	-3	-80	-57	-55	Open collector	6-pin minimold
μPC8112TB								6-pin super minimold

Remark Typical performance. Please refer to ELECTRICAL CHARACTERISTICS in detail.

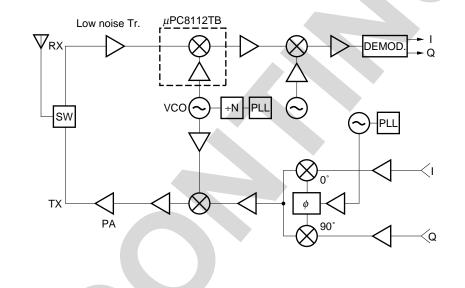
- Cautions 1. The  $\mu$ PC2757 and  $\mu$ PC2758's IIP<sub>3</sub> are calculated with  $\Delta$ IM<sub>3</sub> = 3 which is the same IM<sub>3</sub> inclination as  $\mu$ PC8112. On the other hand, OIP<sub>3</sub> of Standard characterisitcs in page 7 is cross point IP.
  - 2. This document is to be specified for  $\mu$ PC8112TB. The other part number mentioned in this document should be referred to the data sheet of each part number.

#### 3. INTERNAL BLOCK DIAGRAM



#### 4. SYSTEM APPLICATION EXAMPLE

## Digital cordless phone



## 5. PIN EXPLANATION

Pin No.	Pin Name	Applied Voltage (V)	Pin Voltage (V)	Function and Application	Internal Equivalent Circuit
1	RFinput	_	1.2	RF input pin of mixer. This mixer is designed as double balanced type. This pin should be externally coupled to front stage with DC cut capacitor.	
2	GND	GND	_	Ground pin. This pin must be connected to the system ground. Form the ground pattern as wide as possible and the truck length as short as possible to minimize ground impedance.	
5	Vcc	2.7 to 3.3	_	Supply voltage pin. This pin should be connected with bypass capacitor (example: 1 000 pf) to minimize ground impedance.	
6	IFoutput	as same as Vcc voltage through external inductor		IF output pin. This output is configured with open collector of high impedance. This pin should be externally equipped with matching circuit of inductor should be selected as small resistance and high frequency use.	
3	LOinput		1.4	Input pin of local amplifier. This amplifier is designed as differen- tial type. This pin should be externally coupled to local signal source with DC cut capacitor. Recommendable input level is -15 to 0 dBm.	To mixer
4	PS	Vcc or GND	_	Power save control pin. This pin can control ON/OFF operation with bias as follows;Bias: VOperationVPS $\geq 2.5$ ON0 to 0.5OFF	

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#### 6. ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Conditions	Ratings	Unit
Supply Voltage	Vcc	Vcc $T_A = +25^{\circ}C$ , 5 pin and 6 pin		V
Total Circuit Current	lcc	$T_A = +25^{\circ}C$	77.7	mA
Total Power Dissipation PD		Mounted on double sided copper clad $50 \times 50 \times$ 1.6 mm epoxy glass PWB (T <sub>A</sub> = +85°C)	270	mW
Operating Ambient Temperature	TA		-40 to +85	°C
Storage Temperature	Tstg		-55 to +150	°C

#### 7. RECOMMENDED OPERATING RANGE

Parameter	Symbol	MIN.	TYP.	MAX.	Unit	Remarks
Supply Voltage	Vcc	2.7	3.0	3.3	V	5 pin and 6 pin should be applied to same voltage.
Operating Ambient Temperature	TA	-40	+25	+85	°C	
LO Input Power	PLOin	-15	-10	0	dBm	Zs = 50 Ω
RF Input Frequency	<b>f</b> RFin	0.8	1.9	2.0	GHz	
IF Output Frequency	fIFout	100	250	300	MHz	With external matching

# 8. ELECTRICAL CHARACTERISTICS (Unless otherwise specified, $T_A = +25^{\circ}C$ , $V_{CC} = V_{PS} = V_{IFout}$ = 3.0 V, $P_{LOin} = -10 \text{ dBm}$ , $Z_S = Z_L = 50 \Omega$ )

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current	lcc	No input signal	4.9	8.5	11.7	mA
Circuit Current at Power Save Mode	Icc(ps)	Vcc = 3.0 V, Vps = 0.5 V	-	-	0.1	μA
Conversion Gain	CG	$\label{eq:RFin} \begin{array}{l} f_{\text{RFin}} = 900 \mbox{ MHz},  f_{\text{LOin}} = 1  000 \mbox{ MHz} \\ f_{\text{RFin}} = 1.9  \text{GHz},  f_{\text{LOin}} = 1.66  \text{GHz} \end{array}$	11.5 9.5	15 13	17.5 15.5	dB
SSB Noise Figure	SSB•NF	$\label{eq:refin} \begin{array}{l} f_{\text{RFin}} = 900 \mbox{ MHz},  f_{\text{LOin}} = 1  000 \mbox{ MHz} \\ f_{\text{RFin}} = 1.9  \text{GHz},  f_{\text{LOin}} = 1.66  \text{GHz} \end{array}$		9.0 11.2	11 13.2	dB
Saturated Output Power	Po <sub>(sat)</sub>	$\label{eq:resonance} \begin{array}{l} f_{\text{RFin}} = 900 \mbox{ MHz},  f_{\text{LOin}} = 1  000 \mbox{ MHz} \\ f_{\text{RFin}} = 1.9  GHz,  f_{\text{LOin}} = 1.66  GHz \\ (P_{\text{RFin}} = -10  dBm  each) \end{array}$	-6.5 -7	-2.5 -3	_	dBm

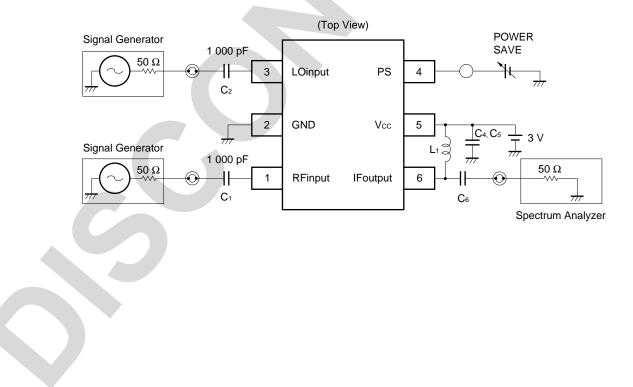
#### 9. STANDARD CHARACTERISTICS FOR REFERENCE

#### (TA = $+25^{\circ}$ C, Vcc = VPS = VIFout = 3.0 V, PLOin = -10 dBm, Zs = ZL = 50 $\Omega$ )

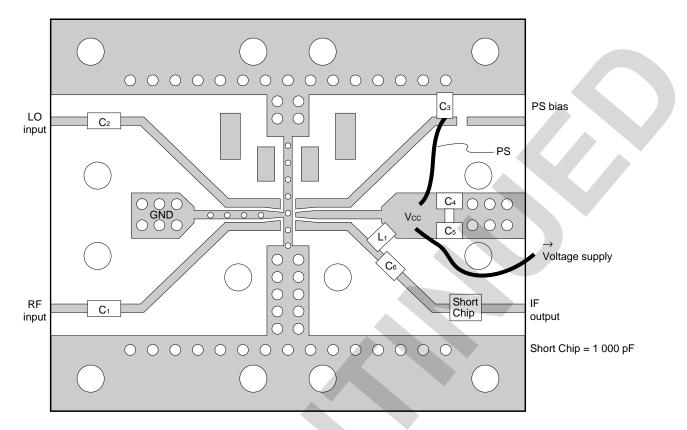
Parameter	Symbol	Test Conditions	Reference	Unit
Conversion Gain	CG	f <sub>RFin</sub> = 1.5 GHz, f <sub>LOin</sub> = 1.6 GHz	13	dB
SSB Noise Figure	SSB•NF	f <sub>RFin</sub> = 1.5 GHz, f <sub>LOin</sub> = 1.6 GHz	11	dB
LO Leakage at RF pin	LOrf	$\label{eq:RFin} \begin{array}{l} f_{\text{RFin}} = 900 \mbox{ MHz},  f_{\text{LOin}} = 1  000 \mbox{ MHz} \\ f_{\text{RFin}} = 1.5  GHz,  f_{\text{LOin}} = 1.6  GHz \\ f_{\text{RFin}} = 1.9  GHz,  f_{\text{LOin}} = 1.66  GHz \end{array}$	-45 -46 -45	dB
RF Leakage at LO pin	RF∟o	$      f_{\text{RFin}} = 900 \text{ MHz}, \      f_{\text{LOin}} = 1 \  000 \text{ MHz} \\       f_{\text{RFin}} = 1.5 \   \text{GHz}, \   \text{f}_{\text{LOin}} = 1.6 \   \text{GHz} \\       f_{\text{RFin}} = 1.9 \   \text{GHz}, \   \text{f}_{\text{LOin}} = 1.66 \   \text{GHz} $	-80 -57 -55	dB
LO Leakage at IF pin	LOif	$      f_{\text{RFin}} = 900 \text{ MHz}, \ f_{\text{LOin}} = 1 \ 000 \text{ MHz} $ $      f_{\text{RFin}} = 1.5 \ \text{GHz}, \ f_{\text{LOin}} = 1.6 \ \text{GHz} $ $      f_{\text{RFin}} = 1.9 \ \text{GHz}, \ f_{\text{LOin}} = 1.66 \ \text{GHz} $	-32 -33 -30	dB
3rd Order Distortion Input Intercept Point <sup>Note</sup>	IIP <sub>3</sub>	frFin = 900 MHz, fLoin = 1 000 MHz frFin = 1.5 GHz, fLoin = 1.6 GHz frFin = 1.9 GHz, fLoin = 1.66 GHz	10 9 7	dBm

**Note** IIP<sub>3</sub> is determined by comparing two method; theoretical calculation and cross point of IM<sub>3</sub> curve. IIP<sub>3</sub> =  $(\Delta IM_3 \times P_{in} + CG - IM_3) \div (\Delta IM_3 - 1)$  (dBm) [ $\Delta IM_3$ : IM<sub>3</sub> curve inclination in linear range]  $\mu$ PC8112's  $\Delta IM_3$  is closer to 3 (theoretical inclination) than  $\mu$ PC2757 and  $\mu$ PC2758 of conventional ICs.

#### **10. TEST CIRCUIT**



#### ★ 11. ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD



Component Number	IF 100 MHz Matching	IF 240 MHz Matching	Remarks
C1 to C5	1 000 pF	1 000 pF	CHIP C
C <sub>6</sub>	5 pF	2 pF	CHIP C
L1	330 nH	84 nH	CHIP L

#### EVALUATION BOARD CHARACTERS AND NOTE

- (1) 35  $\mu$ m thick double-sided copper clad 35 × 42 × 0.4 mm polyimide board
- (2) Back side: GND pattern
- (3) Solder plated patterns
- (4) oO: Through holes
- (5) To mount C<sub>6</sub>, pattern should be cut.
  - Caution Test circuit or print pattern in this sheet is for testing IC characteristics. They are not an application circuit or recommended system circuit.

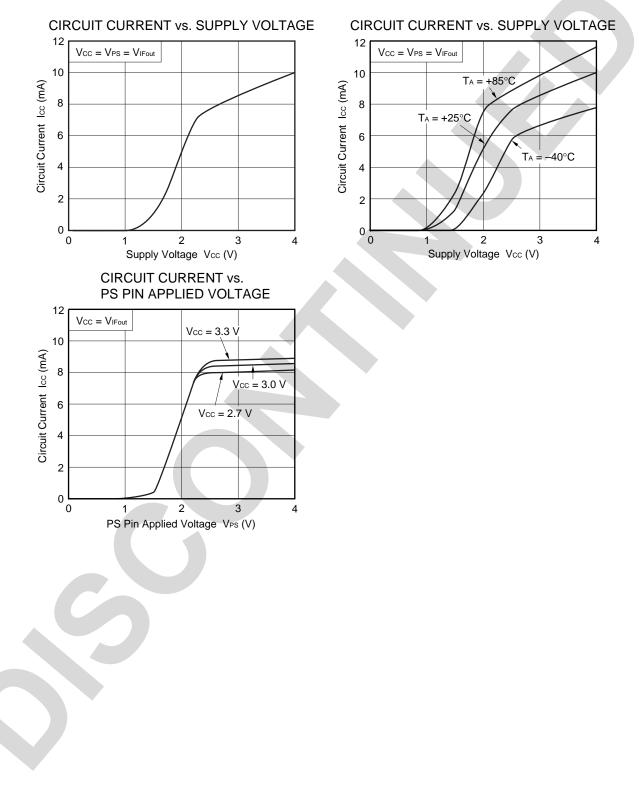
In the case of actual system application, external circuits including print pattern and matching circuit constant of output port should be designed in accordance with IC's S-parameters and environmental components.

Remark External circuits of the IC can be referred to following application notes.

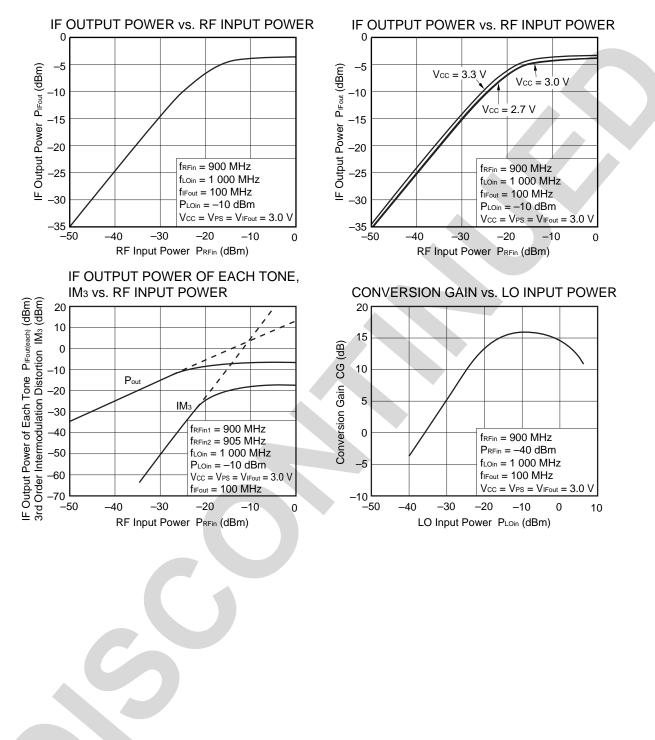
 USAGE AND APPLICATION CHARACTERISTICS OF μPC2757, μPC2758, AND μPC8112, 3-V POWER SUPPLY, 1.9-GHz FREQUENCY DOWN-CONVERTER ICS FOR MOBILE COMMUNICATION (Document No. P11997E)

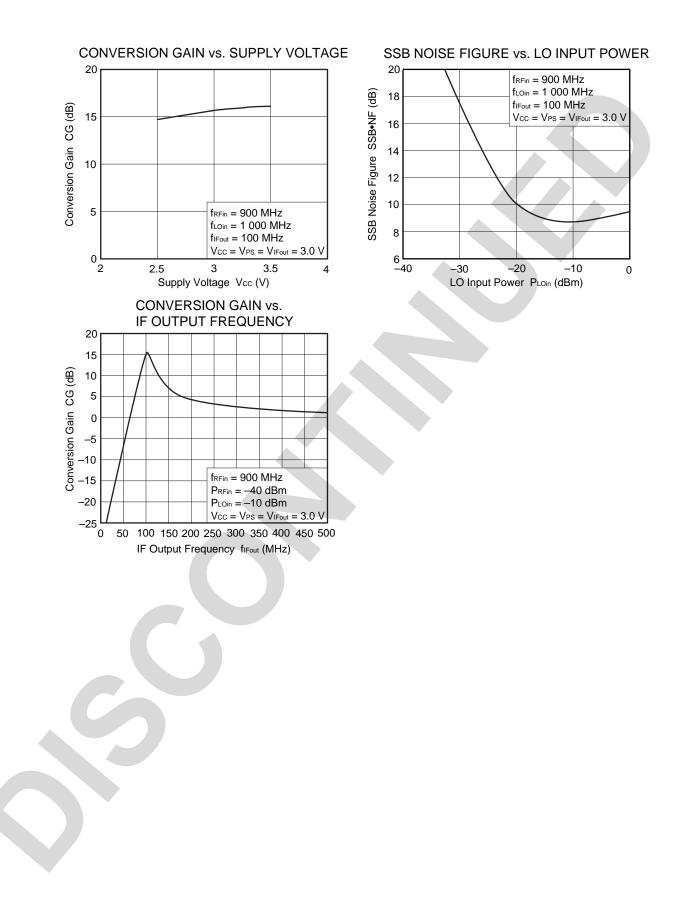
# 12. TYPICAL CHARACTERISTICS (T<sub>A</sub> = +25°C, unless otherwise specified, measured on test circuits)

#### 12.1 Without Signals

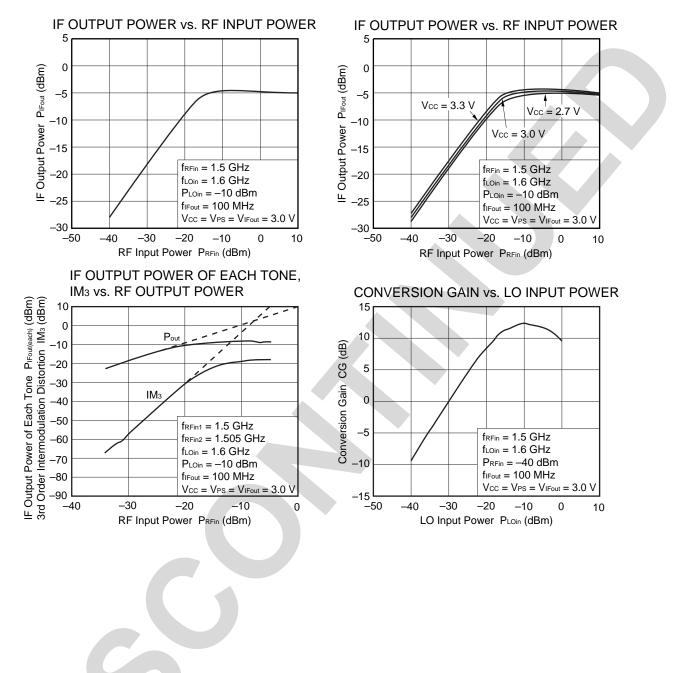


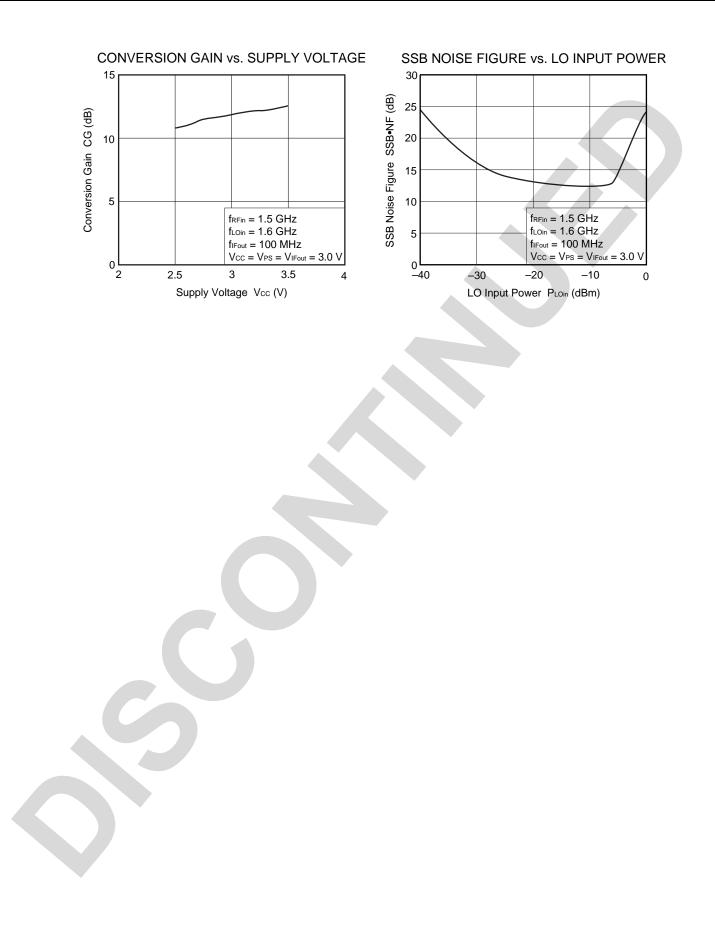
# 12.2 IF 100 MHz Matching (fRFin = 900 MHz)



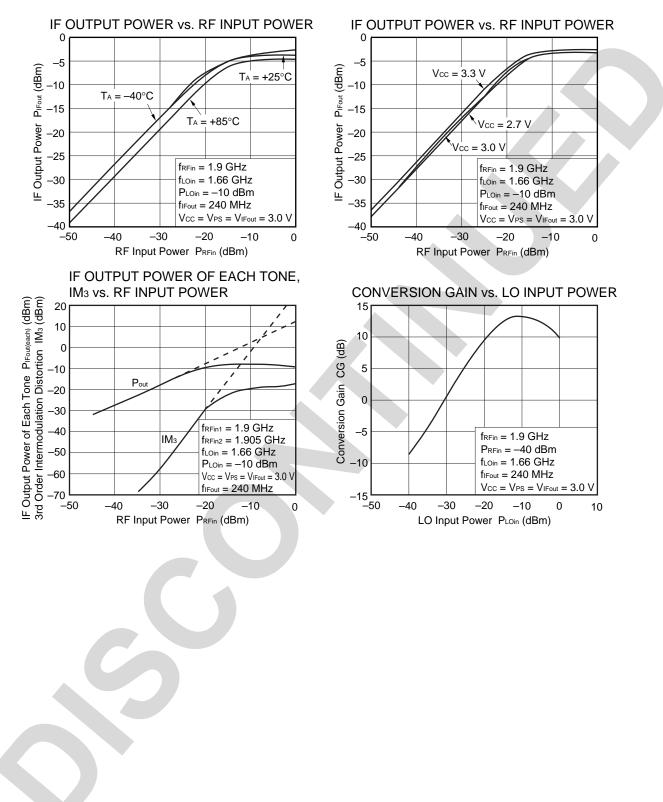


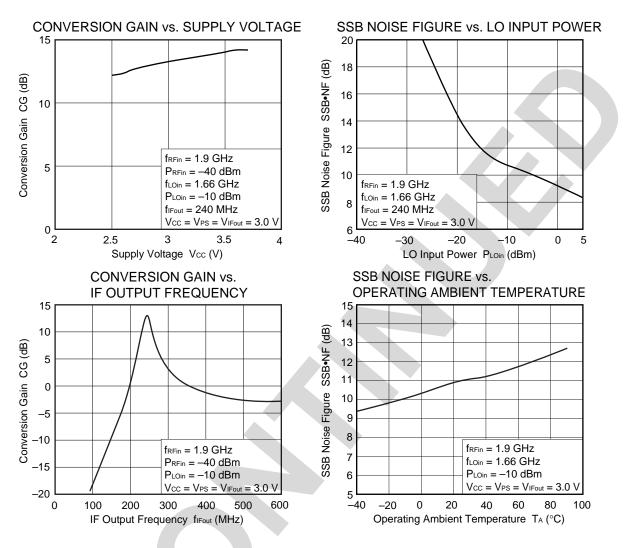
#### 12.3 IF 100 MHz Matching (fRFin = 1.5 GHz)





#### 12.4 IF 240 MHz Matching

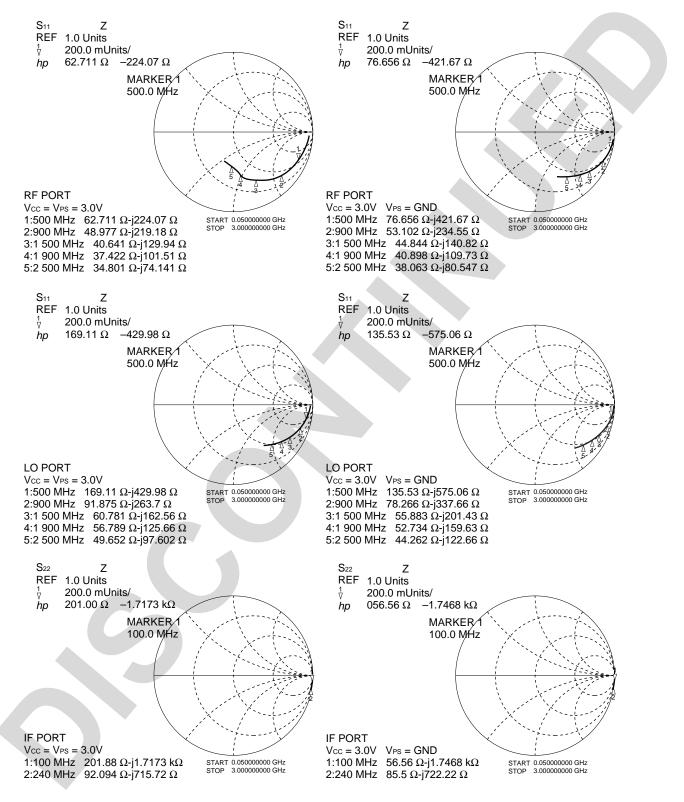




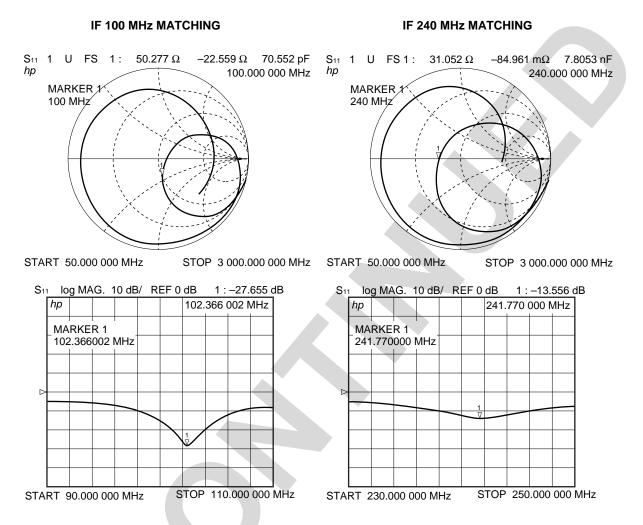
**Remark** The graphs indicate nominal characteristics.

#### 13. S-PARAMETERS

#### 13.1 Calibrated on pin of DUT



#### 13.2 IF Output Matching (Vcc = VPs = VIFout = 3.0 V) -on Test Circuit-(This S11 is monitored at IF connector on test circuit fixture)

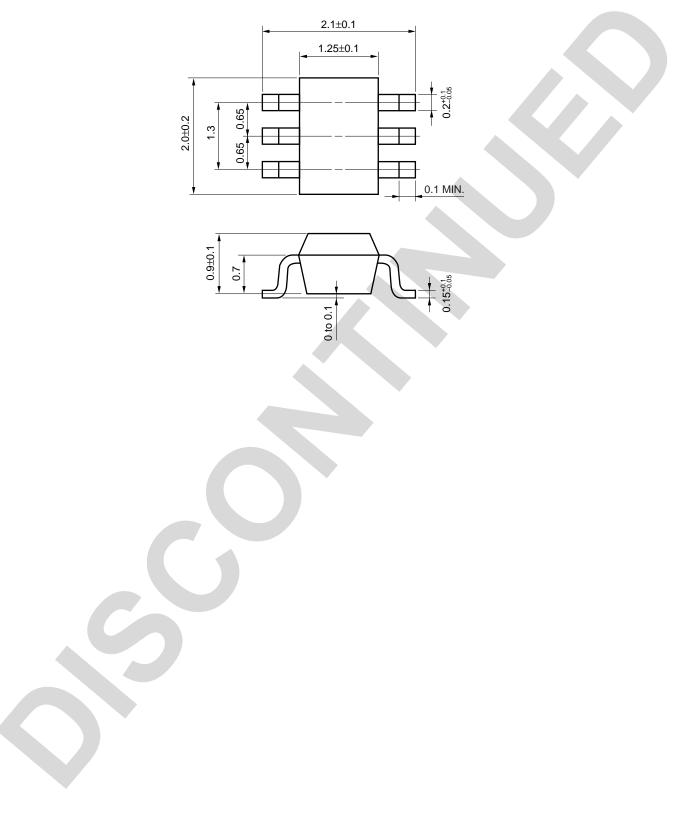


The data in this page are to make clear the test condition of impedance matched to next stage, not specify the recommended condition. The S<sub>11</sub> smith charts of the test fixture setting IC are normalized to  $Z_0 = 50 \Omega$ , because the IC's load is the measurement equipment of 50  $\Omega$  impedance.

In your use, the output return loss value can be helpful information to adjust your circuit matching to next stage.

# 14. PACKAGE DIMENSIONS

# 6-PIN SUPER MINIMOLD (UNIT: mm)



#### **15. NOTE ON CORRECT USE**

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation). Keep the track length of the ground pins as short as possible.
- (3) The bypass capacitor (example: 1 000 pF) should be attached to the Vcc pin.
- (4) The matching circuit should be externally attached to the IF output pin.
- (5) The DC cut capacitor must be each attached to the input and output pins.

#### **16. RECOMMENDED SOLDERING CONDITIONS**

This product should be soldered under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Condition	Recommended Condition Symbol
Infrared Reflow	Package peak temperature: 235°C or below Time: 30 seconds or less (at 210°C) Count: 3, Exposure limit: None <sup>Note</sup>	IR35-00-3
VPS	Package peak temperature: 215°C or below Time: 40 seconds or less (at 200°C) Count: 3, Exposure limit: None <sup>Note</sup>	VP15-00-3
Wave Soldering	Soldering bath temperature: 260°C or below Time: 10 seconds or less Count: 1, Exposure limit: None <sup>Note</sup>	WS60-00-1
Partial Heating	Pin temperature: 300°C Time: 3 seconds or less (per side of device) Exposure limit: None <sup>Note</sup>	_

Note After opening the dry pack, keep it in a place below 25°C and 65% RH for the allowable storage period.

#### Caution Do not use different soldering methods together (except for partial heating).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

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